Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Display conso e/i fscm 49956

Features Provided:

Bipolar and electrically alterable and low power and programmed and high reliability

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Case Outline Source And Designator:

D-2 mil-m-38510

Current Rating Per Characteristic:

100.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Product Name:

1024-bit bipola (256x4) electrically programmable read only memory

Voltage Rating And Type Per Characteristic:

-0.5 volts applied and 7.0 volts applied

Memory Device Type:

Eeprom

Hybrid Technology Type:

Monolithic

Terminal Type And Quantity:

16 printed circuit

Purchase Description Identification:

4995-69-797-3811

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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